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ESC201 Mini-Quiz IV 18/02/2025
Total Marks: 5 Time: 10 minutes

Instructions

- Please write your name and roll number first.
- > Read the question carefully and answer it in the question paper itself.
- 1) For the back-to-back connected diodes shown below, the doping concentration of the p-type Si and n-type Si are $N_A = 10^{18}$ cm⁻³ and $N_D = 10^{16}$ cm⁻³, respectively.
 - (a) Show the direction of electric field at the two depletion regions in the figure itself. (1 mark)

(b) Assume the **current source model** for the diodes and find out the voltage across the diodes D1 (V_{D1}) and D2 (V_{D2}) when a square wave with an amplitude of 5 V is applied to this system. [Take $\eta = 1$, $V_F = V\gamma = 0.7$ V and $V_T = 26$ mV] (4 marks)

